


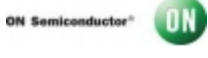
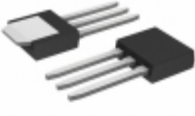
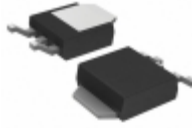


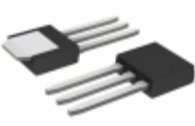

	Hersteller-Teilenummer: NTD4970NT4G
	Hersteller / Marke: AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 30V 38A DPAK
	Datenblätter:  NTD4970NT4G.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 103579 pcs Stock Available.
	Liefern von: Hong Kong
	Versandweg: DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.	

Spezifikationen

Teilenummer	NTD4970NT4G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V 38A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	103579 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	1.38W (Ta), 24.6W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	8.5A (Ta), 36A (Tc)
Rds On (Max) @ Id, Vgs	11 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	8.2nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	774pF @ 15V
Verpackung	Tape & Reel (TR)



















































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Sie können auch interessiert sein:

 <p>NTD4970N-35G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 38A IPAK</p>	 <p>NTD4970N-1 AMI Semiconductor / ON Semiconductor NTD4970N-1 ON</p>	 <p>NTD50N03R-001 AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 7.8A IPAK</p>	 <p>NTD4979NT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 9.4A DPAK-3</p>
 <p>NTD4969NT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 41A DPAK</p>	 <p>NTD4970N ON NTD4970N ON</p>	 <p>NTD4979N-35G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 9.4A IPAK TRIMME</p>	 <p>NTD50N03R AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 7.8A DPAK</p>

heiße Teile

Mehr

 NTD4910N	 NTD4910N-1G	 NTD4910NT4G	 NTD4913N	 NTD4959NHT4G
 NTD4959NT4G	 NTD4960N	 NTD4960N-1G	 NTD4960NT4G	 NTD4963N
 NTD4963N-1	 NTD4963N-1G	 NTD4963N-35G	 NTD4963NT4G	 NTD4965N
 NTD4965N-35G	 NTD4965NT4G	 NTD4969N	 NTD4969N-1	 NTD4969N-1G
 NTD4969NT4G	 NTD4970N	 NTD4970N-1	 NTD4970N-1G	 NTD4970N-35G
 NTD50N03R-001	 NTD50N03R-035	 NTD50N03R-1G	 NTD50N03R-35G	 NTD50N03RG
 NTD50N03RT4	 NTD50N03RT4G	 NTD50N03T4G	 NTD50N06	 NTD5406N
 NTD5406NG	 NTD5406NT4G	 NTD5406T4G	 NTD5407N	 NTD5407NG
 NTD5407NT4G	 NTD5412NT4G	 NTD5413N	 NTD5413NT4G	 NTD5414N
 NTD5414NT4G	 NTD5426NT4G	 NTD5802N	 NTD5802NT4G	 NTD5803N

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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